

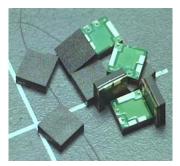
PolyZen Polymer Enhanced Zener Diode Micro-Assemblies

#### PRODUCT: ZEN056V130A24GS

DOCUMENT: SCD 27567 REV LETTER: B REV DATE: APRIL 23, 2009 PAGE NO.: 1 OF 8

**Raychem Circuit Protection Products** 

# **Specification Status: Released**



**GENERAL DESCRIPTION** Tyco Electronics PolyZen devices are polymer enhanced, precision Zener diode microassemblies. They offer resettable protection against multi-Watt fault events without the need for multi-Watt heat sinks.

The Zener diode used for voltage clamping in a PolyZen micro-

assembly is selected due to its relatively flat voltage versus current response. This helps improve output voltage clamping, even when input voltage is high and diode current is large.

An advanced feature of the PolyZen micro-assembly is that the Zener diode is thermally coupled to a resistively nonlinear, polymer PTC (positive temperature coefficient) layer. This PTC layer is fully integrated into the device, and is electrically in series between  $V_{IN}$  and the diode clamped  $V_{OUT}$ .

This advanced PTC layer responds to either extended diode heating or overcurrent events by transitioning from a low to high resistance state, also known as "tripping". A tripped PTC will limit current and generate voltage drop. It helps to protect both the Zener diode and the follow-on electronics and effectively increases the diode's power handling capability.

The polymer enhanced Zener diode helps protect sensitive portable electronics from damage caused by inductive voltage spikes, voltage transients, incorrect power supplies and reverse bias. These devices are particularly suitable for portable electronics and other low-power DC devices.

TYPICAL APPLICATION BLOCK DIAGRAM

# BENEFITS

- Stable Zener diode helps shield downstream electronics from overvoltage and reverse bias
- Trip events shut out overvoltage and reverse bias sources
- Analog nature of trip events minimizes upstream inductive spikes
- Minimal power dissipation requirements
- Single component placement

# **FEATURES**

- Overvoltage transient suppression
- Stable V<sub>z</sub> vs fault current
- Time delayed, overvoltage trip
- Time delayed, reverse bias trip
- Multi-Watt power handling capability
- Integrated device construction
- RoHS Compliant and Halogen Free (HF\*)

# TARGET APPLICATIONS

- DC power port protection in portable electronics
- DC power port protection for systems using barrel jacks for power input
- Internal overvoltage & transient suppression
- DC output voltage regulation

#### Power Supply PolyZen Protected Electronics (External or Internal) GND 2 PolyZen IN 1 Device V<sub>OUT</sub> 3 Regulated $\mathsf{R}_{\mathsf{Load}}$ Output Protected downstream electronics

# *<b>E* Tyco Electronics

308 Constitution Drive Menlo Park, CA 94025-1164 Phone: 800-227-4856 www.circuitprotection.com PolyZen Polymer Enhanced Zener Diode Micro-Assemblies

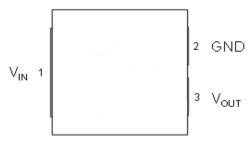
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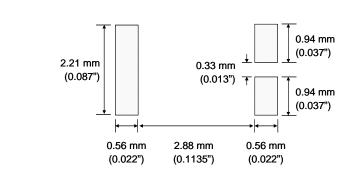
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# **CONFIGURATION INFORMATION**

# **Pin Configuration (Top View)**



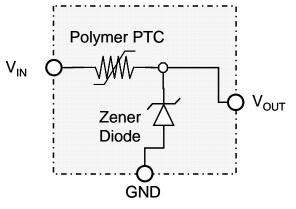


**Recommended Pad Dimensions** 

#### **PIN DESCRIPTION**

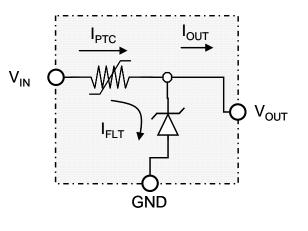
Pin Number	Pin Name	Pin Function
1	V <sub>IN</sub>	V <sub>IN</sub> . Protected input to Zener diode.
2	GND	GND
3	V <sub>OUT</sub>	Vour. Zener regulated voltage output

# **BLOCK DIAGRAM**



# **DEFINITION of TERMS**

I <sub>PTC</sub>	Current flowing through the PTC portion of the circuit
I <sub>FLT</sub>	RMS fault current flowing through the diode
I <sub>OUT</sub>	Current flowing out the V <sub>OUT</sub> pin of the device
Trip Event	A condition where the PTC transitions to a high
	resistance state, thereby significantly limiting IPTC
	and related currents, and significantly increasing
	the voltage drop between V <sub>IN</sub> and V <sub>OUT</sub> .
Trip	Time the PTC portion of the device remains both
Endurance	powered and in a tripped state.



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# **GENERAL SPECIFICATIONS**

Operating Temperature Storage Temperature -40° to +85°C -40° to +85°C

# ELECTRICAL CHARACTERISTICS<sup>1-3, 11</sup> (Typical unless otherwise specified)

Vz <sup>4</sup> (V)		l <sub>zt</sub> <sup>4</sup>	I <sub>но∟D</sub> ⁵ <sup>®</sup> 20⁰С	Leakage Current		R Typ <sup>6</sup>	R <sub>1Max</sub> <sup>7</sup>	V <sub>int</sub> Max <sup>8</sup> (V)		I <sub>FLT</sub> Max <sup>9</sup>		Tripped Power Dissipation <sup>10</sup> Max		
Min	Тур	Max	(A)	(A)	Test Voltage	Max Current (mA)	(Ohms)	(Ohms)	V <sub>INT</sub> Max (V)	Test Current (A)	I <sub>FLT</sub> Max (A)	Test Voltage (V)	Value (W)	Test Voltage (V)
5.45	5.6	5.75	0.1	1.3	5.25	10	0.12	0.18	24V	ЗA	+6 -40	+24 -16V	1.0	24

Note 1: Electrical characteristics determined at 25°C unless otherwise specified.

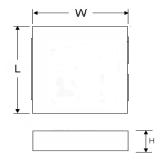
Note 2: This device is intended for limited fault protection. Repeated trip events or extended trip endurance can degrade the device and may affect performance to specifications. Performance impact will depend on multiple factors including, but not limited to, voltage, trip current, trip duration, trip cycles, and circuit design. For details or ratings specific to your application contact Tyco Electronics Circuit Protection Division directly.

- Note 3: Specifications developed using 1.0 ounce 0.045" wide copper traces on dedicated FR4 test boards. Performance in your application may vary.
- Note 4:  $I_{zt}$  is the current at which  $V_z$  is measured ( $V_z = V_{OUT}$ ). Additional  $V_z$  values are available on request.
- Note 5: I<sub>HOLD</sub>: Maximum steady state I<sub>PTC</sub> (current entering or exiting the V<sub>IN</sub> pin of the device) that will not generate a trip event at the specified temperature. Specification assumes I<sub>FLT</sub> (current flowing through the Zener diode) is sufficiently low so as to prevent the diode from acting as a heat source. Testing is conducted with an "open" Zener.
- Note 6: R Typ: Resistance between  $V_{IN}$  and  $V_{OUT}$  pins during normal operation at room temperature.
- Note 7: R<sub>1Max</sub>: The maximum resistance between V<sub>IN</sub> and V<sub>OUT</sub> pins at room temperature, one hour after 1<sup>st</sup> trip or after reflow soldering.
- Note 8: V<sub>INT</sub> Max: V<sub>INT</sub> Max relates to the voltage across the PPTC portion of the PolyZen device (V<sub>IN</sub>-V<sub>OUT</sub>). V<sub>INT</sub> Max is defined as the voltage (V<sub>IN</sub>-V<sub>OUT</sub>) at which typical qualification devices (98% devices, 95% confidence) survived at least 100 trip cycles and 24hours trip endurance at the specified voltage (V<sub>IN</sub>-V<sub>OUT</sub>) and current (I<sub>PTC</sub>). V<sub>INT</sub> Max testing is conducted using a "shorted" load (V<sub>OUT</sub> = 0V). V<sub>INT</sub> Max is a survivability rating, not a performance rating.

Note 9: I<sub>FLT</sub> Max: I<sub>FLT</sub> Max relates to the stead state current flowing through the diode portion of the PolyZen device in a fault condition, prior to a trip event. I<sub>FLT</sub> Max is defined as the current at which typical qualification devices (12 parts per lot from 3 lots) survived 100 test cycles. RMS fault current above I<sub>FLT</sub> Max may permanently damage the diode portion of the PolyZen device. Testing is conducted with <u>NO</u> load connected to V<sub>OUT</sub>, such that I<sub>OUT</sub> = 0. "Test voltage" is defined as the voltage between V<sub>IN</sub> to GND and includes the PolyZen Diode drop. Specification is dependent on the direction of current flow through the diode. I<sub>FLT</sub> Max is a survivability rating, not a performance rating.

- Note 10: The power dissipated by the device when in the "tripped" state, as measured on TE test boards (see note 3).
- Note 11: Specifications based on limited qualification data and subject to change.

# **MECHANICAL DIMENSIONS**



		Min	Typical	Max
Length	L	3.85 mm (0.152")	4 mm (0.16")	4.15 mm (0.163")
Width	W	3.85 mm (0.152")	4 mm (0.16")	4.15 mm (0.163")
Height	Н	1.16mm (0.046")	1.2 mm (0.047")	1.25 mm (0.049")



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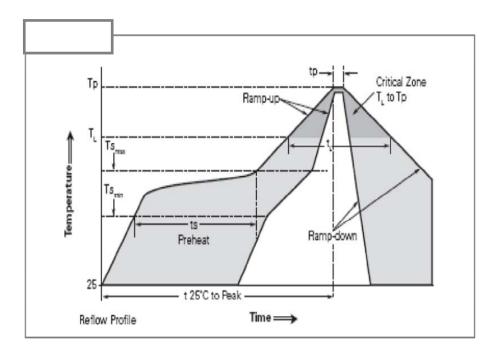
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# SOLDER REFLOW RECOMMENDATIONS:

Classification Reflow Profiles	
Profile Feature	Pb-Free Assembly
Average Ramp-Up Rate (Tsmax to Tp)	3° C/second max.
Preheat	
Temperature Min (Tsmin)	150 °C
Temperature Max (Tsmax)	200 °C
Time (tsmin to tsmax)	60-180 seconds
Time maintained above:	
Temperature (TL)	217 °C
• Time (tL)	60-150 seconds
Peak/Classification Temperature	
(Тр)	260 °C
Time within 5 °C of actual Peak	
Temperature (tp)	20-40 seconds
Ramp-Down Rate	6 °C/second max.
Time 25 °C to Peak Temperature	8 minutes max.



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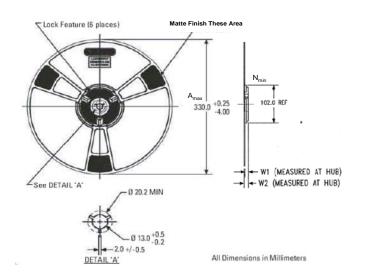
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# PACKAGING

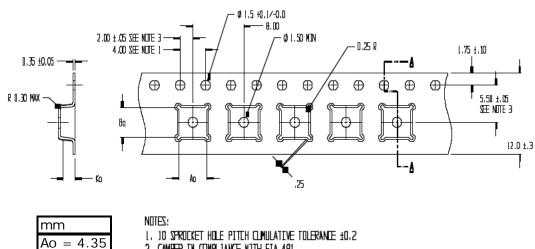
Packaging	Tape & Reel	Standard Box
ZENXXXVXXXAXXGS	4,000	20,000

# **Reel Dimensions for PolyZen Devices**

ĺ	$A_{max} = 330$
	$N_{min} = 102$
	$W_1 = 8.4$
	$W_2 = 11.1$



# **Taped Component Dimensions for PolyZen Devices**



2. CAMBER IN COMPLIANCE WITH EIA 481 Bo = 4.35

Ko = 1.80

- 3. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED
  - AS TRUE POSITION OF POOKET, NOT POEKET HOLE



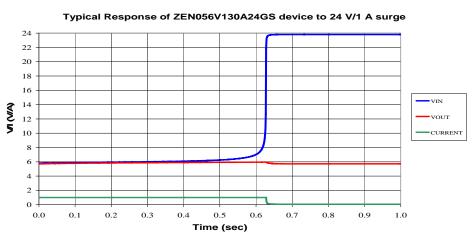
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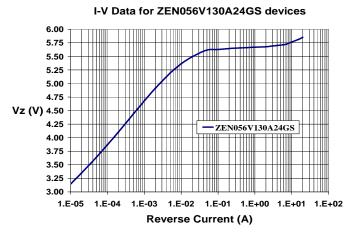
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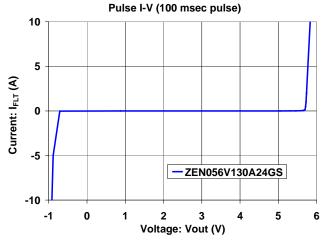
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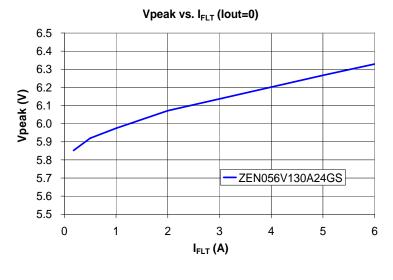
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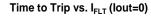
# **TYPICAL CHARACTERISTICS**

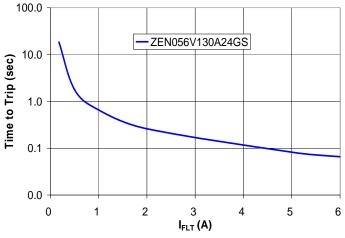












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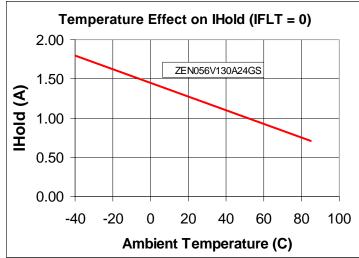
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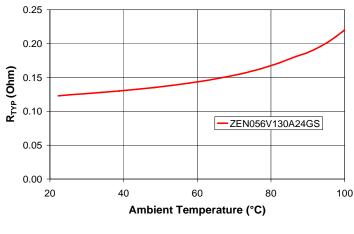
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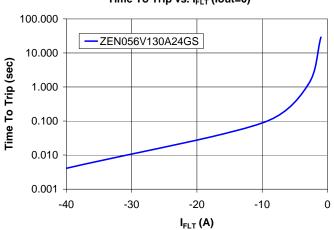
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#### Vpeak vs. I<sub>FLT</sub> (lout=0) 0.0 -0.2 ZEN056V130A24GS -0.4 Vpeak (V) -0.6 -0.8 -1.0 -1.2 -1.4 -40 -30 -20 -10 0 I<sub>FLT</sub> (A)

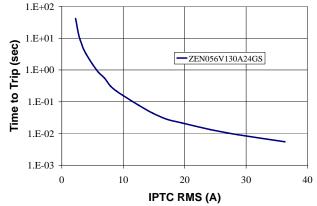


Temperature Effect on R<sub>TYP</sub>





Time to Trip vs. IPTC RMS (I<sub>FLT</sub> = 0)



Time To Trip vs. I<sub>FLT</sub> (lout=0)



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Halogen Free\*

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**Pb-Free** 

## **Materials Information**

**ROHS Compliant** 

Directive 2002/95/EC Compliant



\* Halogen Free refers to: Br≤900ppm, Cl≤900ppm, Br+Cl≤1500ppm.

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